

## SANYO Semiconductors DATA SHEET

P-Channel Silicon MOSFET

# MCH6325 — General-Purpose Switching Device **Applications**

#### **Features**

- · Low ON-resistance.
- · 4V drive

#### **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		-60	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		-2	А
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-8	А
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm <sup>2</sup> X0.8mm)	1.5	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Drain-to-Source Breakdown Voltage	V(BR)DSS	I <sub>D</sub> =-1mA, V <sub>GS</sub> =0V	-60			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =-60V, V <sub>GS</sub> =0V			-1	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±16V, V <sub>DS</sub> =0V			±10	μΑ
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =-10V, I <sub>D</sub> =-1mA	-1.2		-2.6	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =-10V, I <sub>D</sub> =-1A	1.7	2.9		S
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)1	I <sub>D</sub> =-1A, V <sub>G</sub> S=-10V		195	255	mΩ
	R <sub>DS</sub> (on)2	I <sub>D</sub> =-0.5A, V <sub>G</sub> S=-4V		245	345	mΩ

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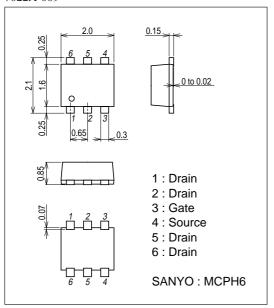
#### MCH6325

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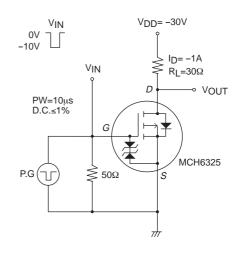
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Input Capacitance	Ciss	V <sub>DS</sub> =-20V, f=1MHz		560		pF
Output Capacitance	Coss	V <sub>DS</sub> =-20V, f=1MHz		52		pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =-20V, f=1MHz		38		pF
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit.		10.5		ns
Rise Time	t <sub>r</sub>	See specified Test Circuit.		10		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit.		68		ns
Fall Time	tf	See specified Test Circuit.		29		ns
Total Gate Charge	Qg	V <sub>DS</sub> =-30V, V <sub>GS</sub> =-10V, I <sub>D</sub> =-2A		12		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =-30V, V <sub>GS</sub> =-10V, I <sub>D</sub> =-2A		1.8		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>DS</sub> =-30V, V <sub>GS</sub> =-10V, I <sub>D</sub> =-2A		2.3		nC
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-2A, V <sub>GS</sub> =0V		-0.84	-1.2	V

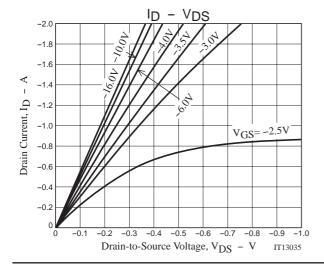
#### **Package Dimensions**

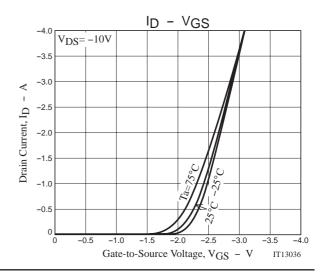
unit : mm (typ) 7022A-009

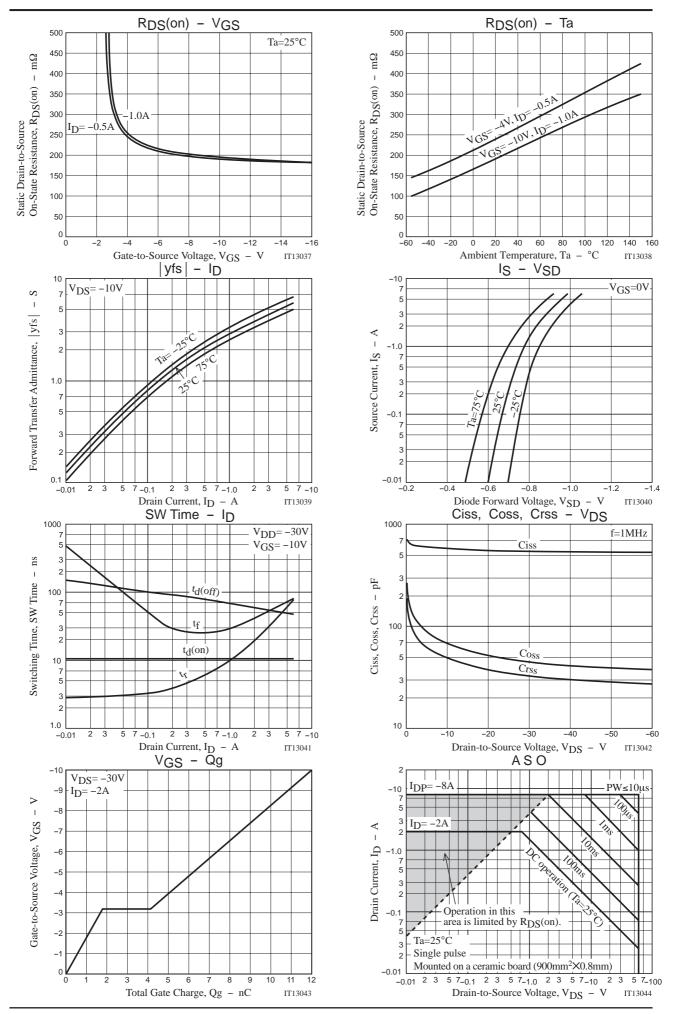


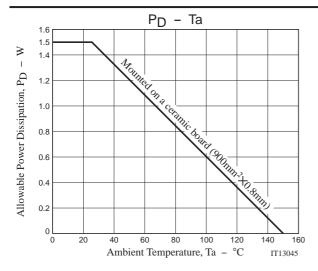
### **Switching Time Test Circuit**











Note on usage: Since the MCH6325 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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